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DATE MAILED: 07/20/2006

APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.	
10/811,137	03/29/2004	Kunio Takeuchi	57810-096 1117		
7590 07/20/2006			EXAMINER		
MCDERMOTT, WILL & EMERY			NGUYEN, DUNG T		
600 13th Street		ART UNIT	PAPER NUMBER		
wasnington, L	OC 20005-3096		2828		

Please find below and/or attached an Office communication concerning this application or proceeding.

		Application	on No.	Applicant(s)	
Office Action Summary		10/811,13	37	TAKEUCHI ET AL.	
		Examine	-	Art Unit	
		Dung (Mid	hael) T. Nguyen	2828	
۔۔۔ Period for l	The MAILING DATE of this communica Reply	tion appears on the	cover sheet with the c	orrespondence ad	dress
WHICH - Extension after SIX - If NO pe - Failure to Any repl	RTENED STATUTORY PERIOD FOR EVER IS LONGER, FROM THE MAI ons of time may be available under the provisions of 3 (6) MONTHS from the mailing date of this community of or reply is specified above, the maximum statut or eptly within the set or extended period for reply will by received by the Office later than three months after patent term adjustment. See 37 CFR 1.704(b).	LING DATE OF TH 37 CFR 1.136(a). In no ever cation. ory period will apply and w , by statute, cause the app	HIS COMMUNICATION ent, however, may a reply be timulated the size of the size	I.  lety filed  the mailing date of this co  (35 U.S.C. § 133).	
Status					
2a)	esponsive to communication(s) filed on the section is <b>FINAL</b> .  2b) ince this application is in condition for one of the section accordance with the practice	☐ This action is n allowance except	for formal matters, pro		e merits is
Disposition	of Claims				
4a 5)⊠ Cl 6)⊠ Cl 7)⊠ Cl 8)□ Cl	laim(s) <u>1-18 and 24-27</u> is/are pending) Of the above claim(s) <u>19-23</u> is/are value (s) <u>24-26</u> is/are allowed. laim(s) <u>1-6,9-14,18 and 27</u> is/are rejectaim(s) <u>7,8 and 15-17</u> is/are objected laim(s) are subject to restriction	withdrawn from cor cted. to.	nsideration.		
Application	Papers				
10)⊠ Th Ap Re	e specification is objected to by the E e drawing(s) filed on <u>29 March 2004</u> oplicant may not request that any objection eplacement drawing sheet(s) including the e oath or declaration is objected to b	is/are: a)⊠ accep on to the drawing(s) b e correction is requir	e held in abeyance. See ed if the drawing(s) is obj	e 37 CFR 1.85(a). ected to. See 37 CF	FR 1.121(d).
Priority und	der 35 U.S.C. § 119				
a)⊠ 1. 2. 3.	knowledgment is made of a claim for All b) Some * c) None of: Certified copies of the priority do Certified copies of the priority do Copies of the certified copies of application from the Internationals the attached detailed Office action for the action for th	cuments have bee cuments have bee the priority docume I Bureau (PCT Rul	n received. n received in Application ents have been receive e 17.2(a)).	on Noed in this National	Stage
	f References Cited (PTO-892)		4) Interview Summary		
3) 🛛 Informat	f Draftsperson's Patent Drawing Review (PTO ion Disclosure Statement(s) (PTO-1449 or PT o(s)/Mail Date <u>07/29/04</u> .		Paper No(s)/Mail Da 5) Notice of Informal Pa 6) Other:		)-152)

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#### **DETAILED ACTION**

#### Election/Restrictions

Applicant's election of Species (claims 1-18 and 24-26) in the reply filed on 05/11/06 is acknowledged. Because applicant did not distinctly and specifically point out the supposed errors in the restriction requirement, the election has been treated as an election without traverse (MPEP § 818.03(a)).

### Claim Rejections - 35 USC § 102

The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(a) the invention was known or used by others in this country, or patented or described in a printed publication in this or a foreign country, before the invention thereof by the applicant for a patent.

Claims 1-3, 5-5, 9-12, 14, and 18 are rejected under 35 U.S.C. 102(a) as being anticipated by JP2002-223039 along with English translation.

With respect to claims 1-3, 10, and 14, Fig. 1 shows a semiconductor laser device comprising:

an emission layer 4 formed on a substrate 1;

a semiconductor layer 8a formed on said emission layer while constituting a convex ridge portion;

a current blocking layer 10 consisting of a semiconductor formed to cover at least the side surfaces of said ridge portion;

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a first metal electrode 11 formed to be in contact with the upper surface of said ridge

portion; and

convex support (dummy) portions (8b, 9b) arranged on both sides of said ridge portion at

a prescribed interval from said ridge portion.

With respect to claim 5, Fig. 1 shows said first metal electrode includes an upper surface

having an irregular shape reflecting the shape of said convex ridge portion, the shape of said

support portions and the shape of said current blocking layer.

With respect to claim 6, Fig. 1 shows the height of portions of said first metal electrode

located on said support portions exceeds that of a portion located on said ridge portion.

With respect to claim 9, Fig. 1 shows side surfaces of said support portions closer to end

surfaces of said semiconductor laser device are arranged inward beyond said end surfaces of said

semiconductor laser device at a prescribed interval.

With respect to claim 11, para.0030 discloses the thickness of the electrode (contact) is 6

um.

With respect to claim 12, para.0028 and 0030 disclose said first metal electrode (contact)

contains a dopant (p mold) having the same conductivity type as said semiconductor layer 8a

constituting said ridge portion.

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With respect to claim 18, para.0029 discloses the current blocking layer containing Al.

## Claim Rejections - 35 USC § 103

The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

Claims 4 and 27 are rejected under 35 U.S.C. 103(a) as being unpatentable over JP2002-223039 along with English translation in view of Goto et al. (2002/0146855). JP2002-223039 disclose all limitations of the claims except for the first metal electrode includes a plurality of metal electrode layers and further a second metal electrode formed on the first metal electrode, superior in adhesiveness to the first metal electrode.

Goto et al. teach in Fig. 1 and Abstract the first metal electrode includes a plurality of metal electrode layers 109-110 and further a second metal electrode 112 formed on the first metal electrode, superior in adhesiveness to the first metal electrode.

it would have been obvious to one having ordinary skill in the art at the time the invention was made to provide JP2002-223039 what is taught by Goto et al. in order to improve the semiconductor laser in reliability and to reduce in operating voltage (Abstract).

Claim 13 is rejected under 35 U.S.C. 103(a) as being unpatentable over JP2002-223039 in view of Hayafuji (5387544). JP2002-223039 disclose in para.0028 said semiconductor layer 8a (AlGaAs) constituting said ridge portion consists of a group III-V compound semiconductor

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and all limitations of the claim except for the dopant, contained in said first metal electrode, having the same conductivity type as said semiconductor layer constituting said ridge portion includes at least one element selected from a group consisting of Zn, Cd, Be, Mg, Ca and Ba.

Hayafuji teaches the dopant of Zinc in the metal electrode (col.1, lines 38-41).

it would have been obvious to one having ordinary skill in the art at the time the invention was made to provide JP2002-223039 what is taught by Hayafuji in order to obtain a better electrical conductivity in the electrode of the laser device.

### Allowable Subject Matter

Claims 7-8 and 15-17 are objected to as being dependent upon a rejected base claim, but would be allowable if rewritten in independent form including all of the limitations of the base claim and any intervening claims. JP2002-223039, Goto et al. and Hayafuji fail to disclose the limitations as recited in the claims.

Claims 24-26 are allowed.

JP2002-223039, Goto et al. and Hayafuji disclose all limitations of the claims but fail to teach the limitation of forming a convex support portion so that the interval between the lower end of said ridge portion and the lower end of said support portion is at least 20 um.

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## Communication Information

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Dung (Michael) T Nguyen whose telephone number is (571) 272-1949. The examiner can normally be reached on 8:30 - 17:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Min Harvey can be reached on (571) 272-1835. The fax phone number for the organization where this application or proceeding is assigned is (703) 872-9306.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 306-3329.

Michael Dung Nguyen

Michael M

07/13/06